

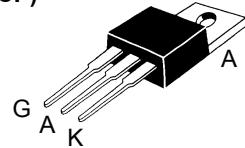
## Switchable Current Regulators

**IXCP 10M35S**  
**IXCY 10M35S**  
**IXCP 10M45S**  
**IXCY 10M45S**

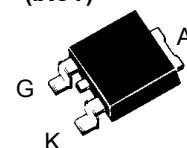
**V<sub>AK</sub> = 350/450 V**  
**I<sub>A(P)</sub> = 2 - 100 mA**  
**R<sub>DYN</sub> = 9 - 900 kΩ**

Symbol	Test Condition	Maximum Ratings		
V <sub>AKR</sub>	T <sub>J</sub> = 25°C to 150°C	10M35S 10M45S	350 450	V V
V <sub>AGR</sub>	T <sub>J</sub> = 25°C to 150°C	10M35S 10M45S	350 450	V V
V <sub>GK</sub>			±20	V
I <sub>D</sub>	T <sub>c</sub> = 25°C		-0.3	A
P <sub>D</sub>	T <sub>c</sub> = 25°C		40	W
T <sub>J</sub>			-55 ... +150	°C
T <sub>stg</sub>			-55 ... +150	°C
T <sub>L</sub>	Temperature for Soldering (max. 10 s)		260	°C
M <sub>D</sub>	Mounting torque with screw M3 (TO-220) with screw M3.5 (TO-220)	0.45/4 0.55/5	Nm/lb.in. Nm/lb.in.	

TO-220 AB (IXCP)



TO-252 AA  
(IXCY)



### Pin connections

- 1 = G, Control terminal;
- 2 and 4 = A (+) Positive terminal
- 3 = K (-), Negative terminal

### Features

- Minimum of 350/450 V breakdown
- Resistor programmable current source
- 40 W continuous dissipation
- International standard packages JEDEC TO-220 and TO-252
- On/Off switchable current source

### Applications

- Start-up circuits for SMPS
- Highly stable voltage sources
- Surge limiters and voltage protection
- Instantaneously reacting resetable fuses
- Soft start-up circuits

Symbol	Test Condition	Characteristic Values		
		(T <sub>J</sub> = 25°C unless otherwise specified)	min.	typ.
V <sub>AKR</sub>	R <sub>K</sub> = 300 Ω, (Fig. 4)	10M35S 10M45S	350 450	V V
I <sub>A(P)</sub>	V <sub>D</sub> = 10 V; R <sub>K</sub> = 300 Ω; (Fig. 5)		7	10
V <sub>G(off)</sub>	I <sub>D</sub> = 100 μA; V <sub>D</sub> = 300 V I <sub>D</sub> = 100 μA; V <sub>D</sub> = 400 V Fig. 4	10M35S 10M45S	-5 -5	V V
I <sub>AV</sub>	V <sub>D</sub> = 300 V; V <sub>GK</sub> = -10 V V <sub>D</sub> = 400 V; V <sub>GK</sub> = -10 V Fig. 4	10M35S 10M45S		25 μA 25 μA
ΔV <sub>AK</sub> /Δ I <sub>A(P)</sub>	Dynamic resistance; V <sub>D</sub> = 10 V R <sub>K</sub> = 300 Ω; (Fig. 4)		10	kΩ
R <sub>thJC</sub>	Thermal Resistance junction-to-case			3.1 K/W
R <sub>thJA</sub>	Thermal Resistance junction-to-ambient TO-220 TO-252			80 K/W 100 K/W

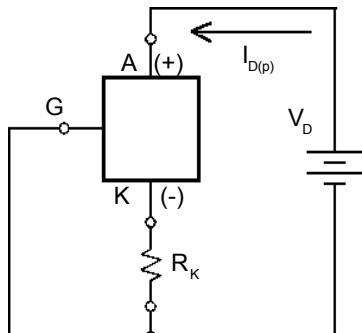


Fig. 1 Resistor  $R_K$  in series with negative pin to achieve different current levels

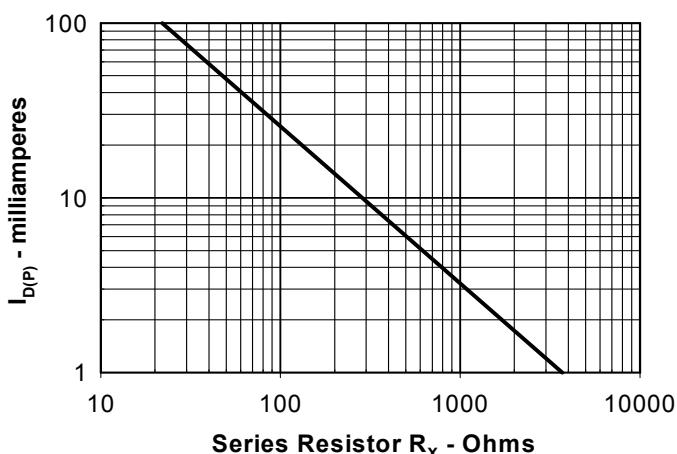


Fig. 2. Plateau current versus external resistance

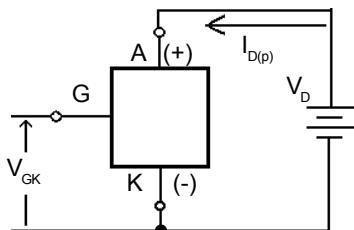


Fig. 3. Current regulator controlled by  $V_G$

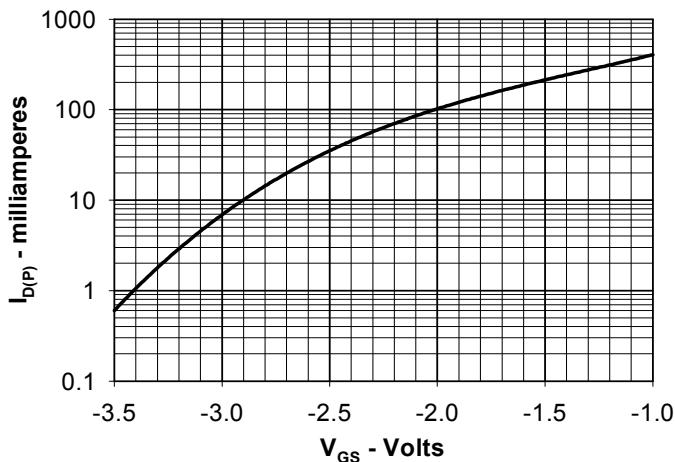
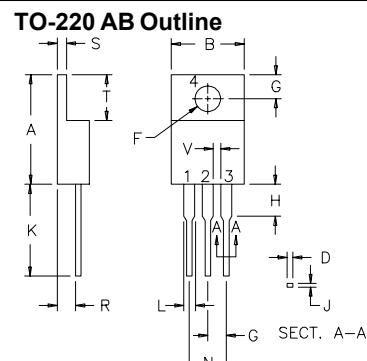
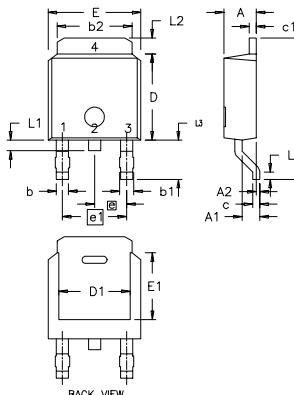


Fig. 4. Plateau current versus applied input voltage



Dim.	Millimeter Min.	Millimeter Max.	Inches Min.	Inches Max.
A	14.23	16.51	.560	.650
B	9.66	10.66	.380	.420
C	3.56	4.82	.140	.190
D	0.64	0.89	.025	.035
F	3.54	4.06	.139	.161
G	2.29	2.79	.090	.110
H	—	6.35	—	.250
J	0.51	0.76	.020	.030
K	12.70	14.73	.500	.580
L	1.15	1.77	.045	.070
N	4.83	5.33	.190	.210
Q	2.54	3.42	.100	.135
R	2.04	2.49	.080	.115
S	0.64	1.39	.025	.055
T	5.85	6.85	2.30	2.70
V	1.15	—	.045	—

#### TO-252 AA Outline



Dim.	Millimeter Min.	Millimeter Max.	Inches Min.	Inches Max.
A	2.19	2.38	0.086	0.094
A1	0.89	1.14	0.035	0.045
A2	0	0.13	0	0.005
b	0.64	0.89	0.025	0.035
b1	0.76	1.14	0.030	0.045
b2	5.21	5.46	0.205	0.215
c	0.46	0.58	0.018	0.023
c1	0.46	0.58	0.018	0.023
D	5.97	6.22	0.235	0.245
D1	4.32	5.21	0.170	0.205
E	6.35	6.73	0.250	0.265
E1	4.32	5.21	0.170	0.205
e	2.28 BSC	—	0.090 BSC	—
e1	4.57 BSC	—	0.180 BSC	—
H	9.40	10.42	0.370	0.410
L	0.51	1.02	0.020	0.040
L1	0.64	1.02	0.025	0.040
L2	0.89	1.27	0.035	0.050
L3	2.54	2.92	0.100	0.115

IXYS reserves the right to change limits, test conditions, and dimensions.

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4,850,072 4,931,844 5,017,508 5,049,961 5,187,117 5,486,715  
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